NSN 5961-01-088-4899



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-088-4899 **Inclosure Material:** Glass **Overall Length:** 0.357 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.235 inches **End Application:** Join stars target radar system; defense meteorological satelllite program (dmsp); aircraft, stratolifter c-135; missile, minuteman lgm-30; helicopter, search and rescue, hh-60h; helicopter, mh-53e; aircraft, airlifter c-17a; helicopter, carrier based asw, sh-60f; support equipment, b-52 aircraft; aircraft, ac-130h, mc-130h, ec-130e, hc-130 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 37.8 breakdown voltage, instantaneous and 30.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Weapon system essential; junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/507 government specification Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization: